

Amendments to the Specification

Please amend the Title as follows.

~~Capacitors, Dynamic Random Access Memory (DRAM) Circuitry, Methods of~~
Forming Capacitors, and Methods of Forming DRAM Circuitry

At page 1, prior to the Technical Field section, please enter the following new paragraph.

RELATED PATENT DATA

This patent resulted from a continuation application of U.S. Patent Application Serial No. 09/198,034, filed November 23, 1998, now U.S. Patent No. 6,717,201.